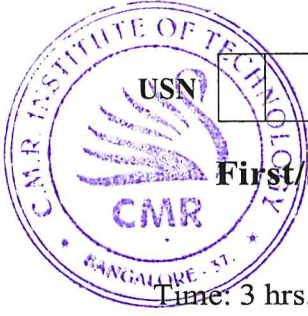


CBCS SCHEME



17ELN15/25

First/Second Semester B.E. Degree Examination, July/August 2022 Basic Electronics

Time: 3 hrs.

Max. Marks: 100

Note: Answer any FIVE full questions, choosing ONE full question from each module.

Module-1

- Explain the V-I characteristics of p-n junction diode. (08 Marks)
 - With neat circuit diagram and waveform explain the working of full wave bridge rectifier. (08 Marks)
 - Derive the relationship between α and β . Also calculate the α value and β value of a transistor. If $I_{\beta} = 100\mu\text{A}$ and $I_C = 2\text{mA}$. (04 Marks)

OR

- With a neat diagram, explain the Input-Output characteristics of a transistor in common base configuration. (08 Marks)
 - With neat circuit diagram and waveforms, explain the working of a half-wave rectifier. (08 Marks)
 - Explain briefly capacitor filter circuit. (04 Marks)

Module-2

- Explain the characteristic of Ideal operational amplifier. (06 Marks)
 - What is DC load line? Explain with neat circuit the operation of voltage divider bias circuit. (08 Marks)
 - Derive the output expression of Op-Amp differentiator. (06 Marks)

OR

- Calculate the output voltage of a three input inverting summing amplifier, given $R_1 = 200\text{K}\Omega$, $R_2 = 250\text{K}\Omega$, $R_3 = 500\text{K}\Omega$, $R_f = 1\text{M}\Omega$, $V_1 = -2\text{V}$, $V_2 = -1\text{V}$ and $V_3 = +3\text{V}$. (06 Marks)
 - For the circuit shown in Fig.Q.4(b) find the Q-point values and draw DC-load line, where $V_{BE} = 0.7\text{V}$ and $\beta = 50$. (06 Marks)

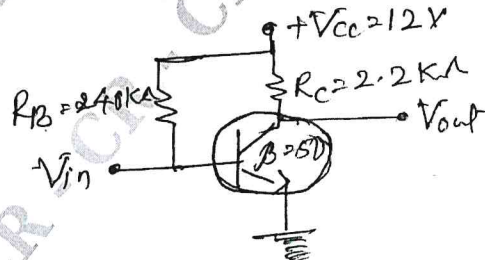


Fig.Q.4(b)

- Explain briefly inverting and non-inverting operational amplifiers. (08 Marks)

Module-3

- 5 a. Convert:
- $(1101101)_2 = (?)_{10}$ and $(101.01)_2 = (?)_{10}$
 - $(48350)_{10} = (?)_{16} = (?)_8$
 - $(FA876)_{16} = (?)_8 = (?)_{10}$
 - $(237)_8 = (?)_{16} = (?)_{10}$. (08 Marks)
- b. Perform the subtraction:
- $(22 - 17)_{10}$ by using 1's complement. (04 Marks)
 - $(11010)_2 - (10000)_2$ by using 2's complement. (08 Marks)
- c. State and prove De-Morgan's theorems. (08 Marks)

OR

- 6 a. Explain the full adder circuit with circuit diagram, truth table. (05 Marks)
- b. What are universal gates? Realize AND and OR gates using NAND gates. (05 Marks)
- c. Simplify: $y = \overline{ABCD} + \overline{A}BCD + A\overline{BCD} + ABCD$. (05 Marks)
- d. Draw and explain half adder circuit. (05 Marks)

Module-4

- 7 a. Explain the operation of NOR Latch with symbol, circuit diagram and truth table. (06 Marks)
- b. Explain with neat block diagram architecture of 8051 microcontroller. (08 Marks)
- c. Explain the working of clocked RS-flip flop using NAND-gates. (06 Marks)

OR

- 8 a. Write a note on NAND-gate latch. (06 Marks)
- b. With the help of block diagram, explain the microcontroller based stopper motor control system. (08 Marks)
- c. Explain R-S flip-flop with diagram and truth table. (06 Marks)

Module-5

- 9 a. With the help of block diagram, explain the communication system. (06 Marks)
- b. Define Modulation. Derive mathematical expression for amplitude modulation, draw waveforms. (06 Marks)
- c. Explain the construction and working principle of LVDT. (08 Marks)

OR

- 10 a. A carrier of 1MHz, with 400W of its power is amplitude modulated with a sinusoidal signal of 2500Hz. The depth of modulation is 75%. Calculate the side band frequency, Bandwidth, the power in the side bands and the total power in the modulated wave. (06 Marks)
- b. List the differences between Amplitude Modulation and frequency modulation. (06 Marks)
- d. Explain the piezoelectric transducer and photo electric transducer. (08 Marks)
